

TrenchT4[™] Power MOSFET

IXTP270N04T4 IXTH270N04T4

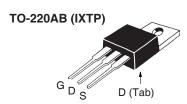
 $V_{DSS} = 40V$ $I_{D25} = 270A$ $R_{DS(on)} \le 2.4m\Omega$

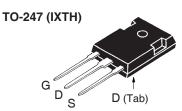
N-Channel Enhancement Mode Avalanche Rated



Symbol	Test Conditions	Maximum Ratings		
V _{DSS}	T _J = 25°C to 175°C	40	V	
V _{DGR}	$T_{_{\mathrm{J}}} = 25^{\circ}\text{C}$ to 175°C, $R_{_{\mathrm{GS}}} = 1\text{M}\Omega$	40	V	
V _{GSM}	Transient	±15	V	
I _{D25}	T _C = 25°C	270	A	
LRMS	Lead Current Limit, RMS	160	Α	
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	800	Α	
I _A	T _C = 25°C	135	A	
E _{as}	$T_{c} = 25^{\circ}C$	750	mJ	
I _A	T _C = 25°C	270	A	
E _{AS}	T _C = 25°C	350	mJ	
P_{D}	T _c = 25°C	375	W	
T _J		-55 +175	°C	
T _{JM}		175	°C	
T _{stg}		-55 +175	°C	
T,	Maximum Lead Temperature for Soldering	300	°C	
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C	
M _d	Mounting Torque	1.13 / 10	Nm/lb.in	
Weight	TO-220 TO-247	3 6	g g	

SymbolTest ConditionsChara(T _J = 25°C Unless Otherwise Specified)Min.			acterist Typ.		
BV _{DSS}	$V_{GS} = 0V, I_{D} = 250 \mu A$	40			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0		4.0	V
I _{GSS}	$V_{GS} = \pm 15V, V_{DS} = 0V$			±200	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$			5	μΑ
	T_{J}	= 150°C		750	μΑ
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 50A, Note 1$			2.4	mΩ





G = Gate	D	=	Drain
S = Source	Tab	=	Drain

Features

- International Standard Packages
- 175°C Operating Temperature
- High Current Handling Capability
- Avalanche Rated
- Low R_{DS(on)}

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- Synchronous Buck Converters
- High Current Switching Power Supplies
- Battery Powered Electric Motors
- Resonant-Mode Power Supplies
- Electronics Ballast Application
- Class D Audio Amplifiers



SymbolTest ConditionsCharacteristics $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		acteristic Typ.	Values Max.	
g_{fs}	$V_{DS} = 10V, I_{D} = 60A, \text{ Note } 1$	90	150	S
R_{Gi}	Gate Input Resistance		1.4	Ω
C _{iss}			9140	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		1450	pF
C _{rss}			980	pF
t _{d(on)}	Resistive Switching Times		18	ns
t _r	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 135A$		28	ns
t _{d(off)}	$R_{G} = 2\Omega$ (External)		72	ns
t _r	G (· · · · · ·)		23	ns
Q _{g(on)}			182	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		45	nC
\mathbf{Q}_{gd}			67	nC
R _{thJC}	TO-220 TO-247		0.50 0.21	0.40 °C/W °C/W °C/W

Source-Drain Diode

Symbol	Test Conditions	Chara	acteristi	c Values	
$(T_J = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max.	
Is	$V_{GS} = 0V$			270	Α
I _{SM}	Repetitive, Pulse width limited by T_{JM}			1080	Α
V _{SD}	$I_F = 100A, V_{GS} = 0V, Note 1$			1.4	V
t _{rr}	I _F = 150A, V _{GS} = 0V		48		ns
I _{RM}	-di/dt = 100A/µs		1.8		Α
Q_{RM}	$V_R = 30V$		43		nC

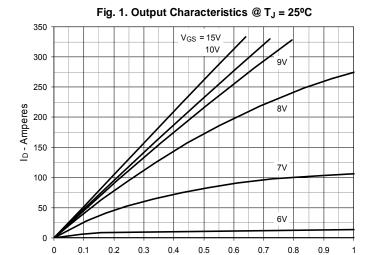
Notes: 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

2. On through-hole packages, $R_{{\rm DS(on)}}$ Kelvin test contact location must be 5mm or less from the package body.

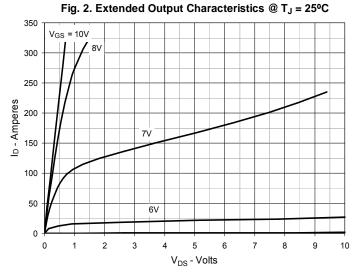
PRELIMINARY TECHNICAL INFORMATION

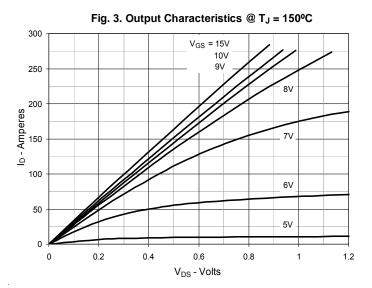
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

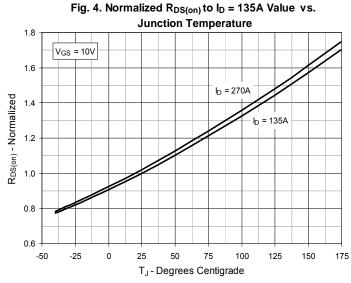


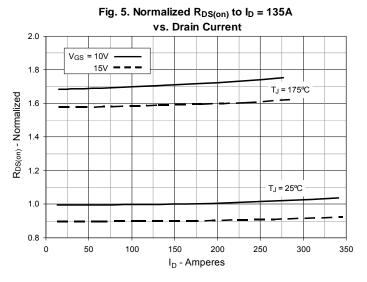


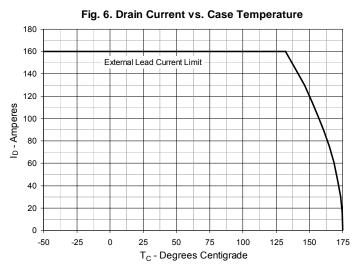
V_{DS} - Volts



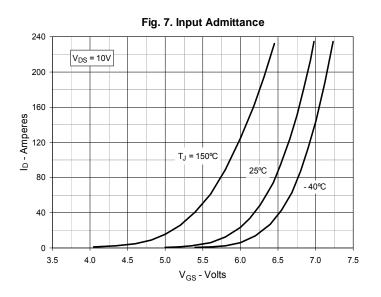


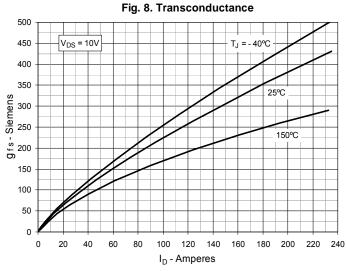


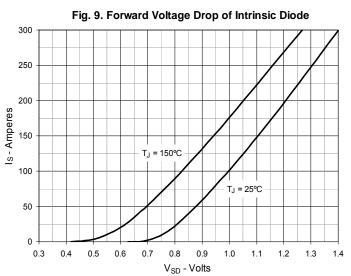


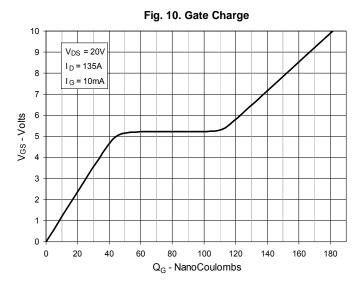


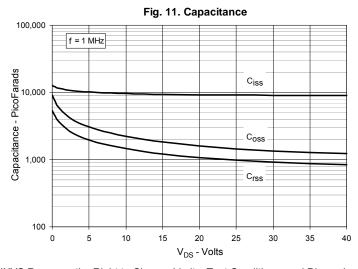


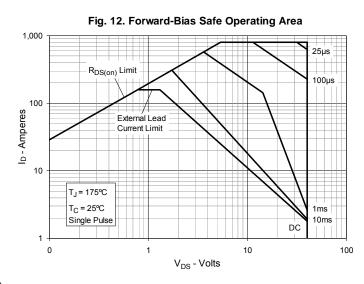






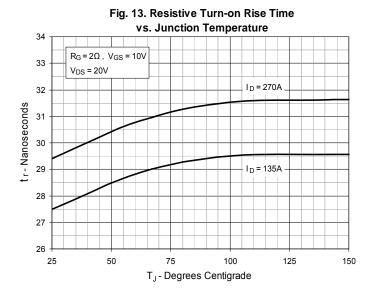


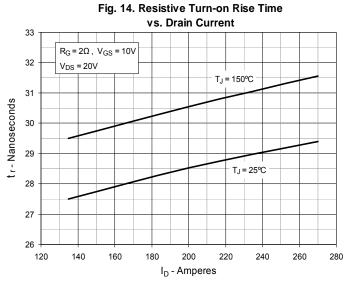


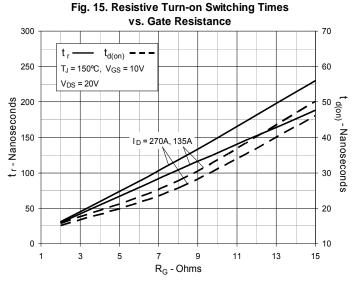


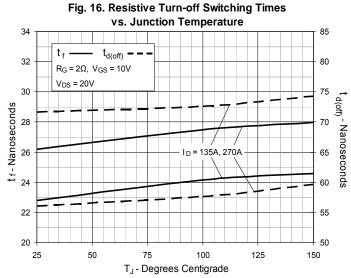
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

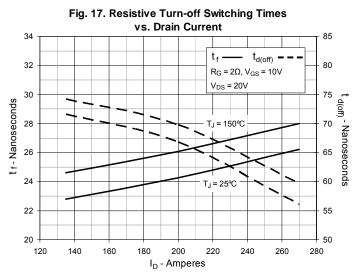


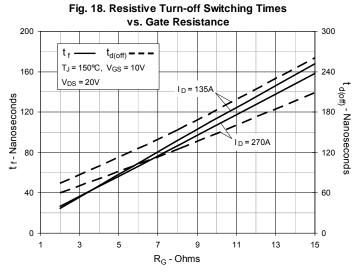














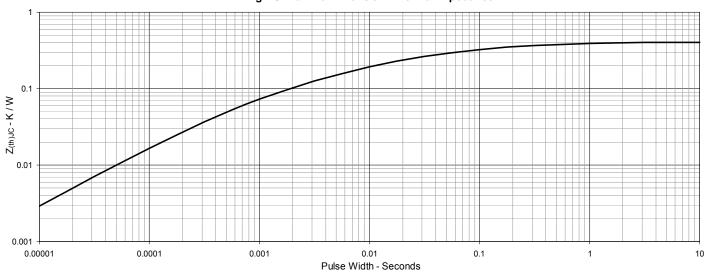
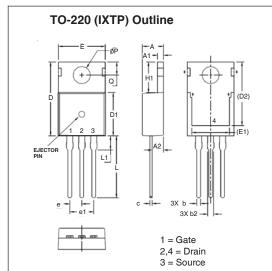
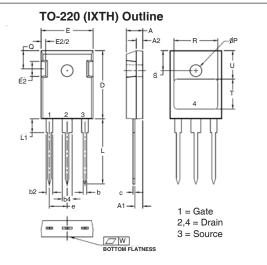


Fig. 19. Maximum Transient Thermal Impedance



CVII	INC	HES	MILLIM	ETERS
SYM	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ь	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
С	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
е	.100	BSC	2.54 BSC	
e1	.200	BSC	5.08 BSC	
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



	INCH	IFS.	MILLIMETERS	
SYM	MIN	MAX	MIN	MAX
Α	190،	,205	4.83	5.21
A1	087،	.100	2.21	2,54
A2	.075	,085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	,085	1.91	2.16
b4	.115	.126	2.92	3,20
С	.023	,033	0.58	0,84
D	.820	,840	20,83	21.34
Е	,620	,635	15,75	16,13
E2	.175	.195	4.44	4.95
е		BSC	5,45	BSC
L	.780	.810	19.81	20.57
L1	.160	.177	4.06	4.50
Q	.220	.240	5.59	6.10
R	,520	,540	13,21	13.72
S	.242	BSC	6.15 BSC	
Ť	,355	,375	9.02	9.53
U	.345	.370	8.76	9.40
ØΡ	.140	144،	3,55	3.66
W	.000	.004	0.00	0,10

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

